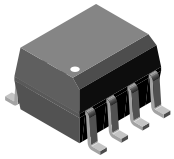
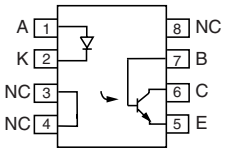
Optocoupler, Phototransistor Output, with Base Connection in SOIC-8 Package



i179002



FEATURES

- Isolation test voltage, 4000 V_{RMS}
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

Pb-free

e3

RoHS COMPLIANT

DESCRIPTION

The VO211AT, VO212AT, VO213AT are optically coupled pairs with a gallium arsenide infrared LED and silicon NPN phototransistor. Signal information, including a DC level, can be transmitted by the device while maintaining a high degree of electrical isolation between input and output.
The VO211AT, VO212AT, VO213AT comes in a standard SOIC-8 small outline package for surface mounting which makes it ideally suited for high density applications with limited space.

AGENCY APPROVALS

- UL1577, file no. E52744 system code Y
- CUL - file no. E52744, equivalent to CSA bulletin 5A
- DIN EN 60747-5-5 (VDE 0884) available with option 1

ORDER INFORMATION

PART	REMARKS
VO211AT	CTR > 20 %, SOIC-8
VO212AT	CTR > 50 %, SOIC-8
VO213AT	CTR > 100 %, SOIC-8

ABSOLUTE MAXIMUM RATINGS

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
INPUT				
Peak reverse voltage		V_R	6	V
Peak forward current	1 µs, 300 pps	I_{FM}	1	A
Forward continuous current		I_F	60	mA
Power dissipation		P_{diss}	90	mW
Derate linearly from 25 °C			1.2	mW/°C
OUTPUT				
Collector emitter breakdown voltage		BV_{CEO}	30	V
Emitter collector breakdown voltage		BV_{ECO}	7	V
Collector base breakdown voltage		BV_{CBO}	70	V
$I_{Cmax.\ DC}$		$I_{Cmax.\ DC}$	50	mA
$I_{Cmax.}$	t < 1 ms	$I_{Cmax.}$	100	mA
Power dissipation		P_{diss}	150	mW
Derate linearly from 25 °C			2	mW/°C
COUPLER				
Isolation test voltage		V_{ISO}	4000	V_{RMS}
Total package dissipation	LED and detector	P_{tot}	240	mW
Derate linearly from 25 °C			3.2	mW/°C
Storage temperature		T_{stg}	- 40 to + 150	°C
Operating temperature		T_{amb}	- 40 to + 100	°C
Soldering time	at 260 °C	T_{sld}	10	s

Note

T_{amb} = 25 °C, unless otherwise specified.
Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

ELECTRICAL CHARACTERISTCS							
PARAMETER	**TEST CONDITION**	**PART**	**SYMBOL**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
INPUT							
Forward voltage	I_F = 10 mA		V_F		1.3	1.5	V
Reverse current	V_R = 6 V		I_R		0.1	100	µA
Capacitance	V_R = 0 V		C_O		13		pF
OUTPUT							
Collector emitter breakdown voltage	I_C = 100 µA		BV_{CEO}	30			V
Emitter collector breakdown voltage	I_E = 10 µA		BV_{ECO}	7			V
Collector base breakdown voltage	I_C = 100 µA		BV_{CBO}	100			V
Collector base current			I_{CBO}			1	nA
Emitter base current			I_{EBO}			1	nA
Collector dark current	V_{CE} = 10 V		I_{CEO}		5	50	nA
Collector emitter capacitance	V_{CE} = 0 V		C_{CE}		10		pF
Saturation voltage, collector emitter	I_F = 10 mA		V_{CEsat}			0.4	V
COUPLER							
Isolation test voltage	1 s		V_{ISO}	4000			V_{RMS}

Note

T_{amb} = 25 °C, unless otherwise specified.
Minimum and maximum values were tested requierements. Typical values are characteristics of the device and are the result of engineering evaluations. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO							
PARAMETER	**TEST CONDITION**	**PART**	**SYMBOL**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
Current transfer ratio	I_F = 10 mA, V_{CE} = 5 V	VO211AT	CTR	20	50		%
		VO212AT	CTR	50	80		%
		VO213AT	CTR	100	130		%

SWITCHING CHARACTERISTICS							
PARAMETER	**TEST CONDITION**	**PART**	**SYMBOL**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
Turn-on time	I_C = 2 mA, R_L = 100 Ω, V_{CC} = 10 V		t_{on}		3		µs
Turn-off time	I_C = 2 mA, R_L = 100 Ω, V_{CC} = 10 V		t_{off}		3		µs
Rise time	I_C = 2 mA, R_L = 100 Ω, V_{CC} = 10 V		t_r		3		µs
Fall time	I_C = 2 mA, R_L = 100 Ω, V_{CC} = 10 V		t_f		2		µs

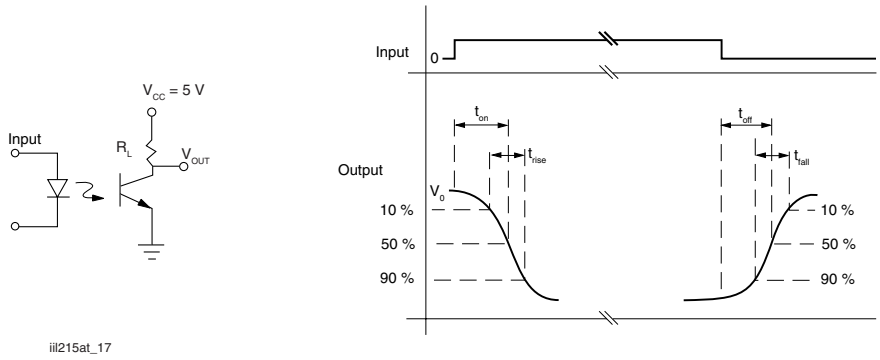
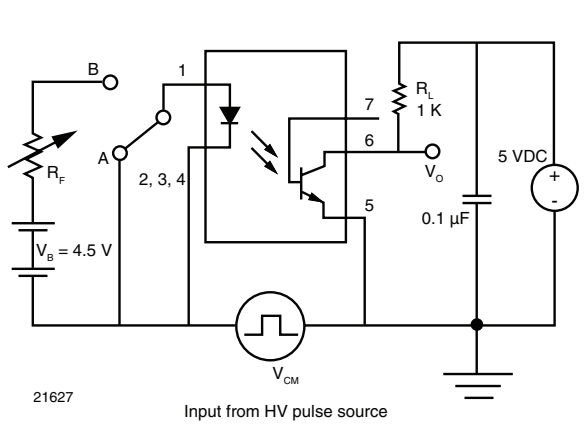


Fig. 1 - Switching Test Circuit

COMMON MODE TRANSIENT IMMUNITY						
PARAMETER	**TEST CONDITION**	**SYMBOL**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
Common mode transient immunity at logic high	V_{CM} = 1000 V_{P-P}, R_L = 1 kΩ, I_F = 0 mA	$\|C_{MH}\|$		5000		V/µs
Common mode transient immunity at logic low	V_{CM} = 1000 V_{P-P}, R_L = 1 kΩ, I_F = 10 mA	$\|C_{ML}\|$		5000		V/µs



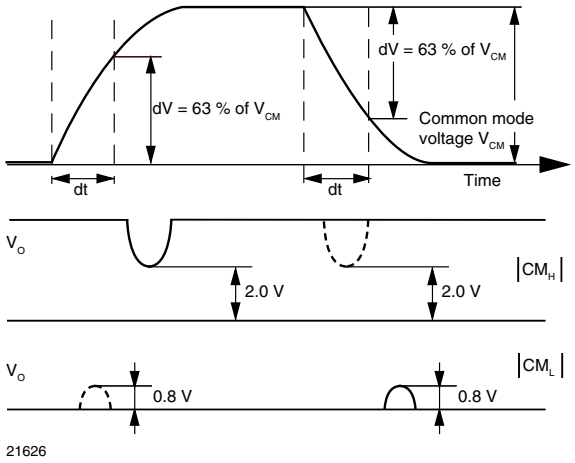


Fig. 2 - Test Circuit for Common Mode Transient Immunity

SAFETY AND INSULATION RATINGS						
PARAMETER	**TEST CONDITION**	**SYMBOL**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
Climatic classification (according to IEC 68 part 1)				40/100/21		
Polution degree				2		
Comparative tracking index		CTI	175		399	
Isolation test voltage	1 s	V_{ISO}	4000			V_{RMS}
Peak transient overvoltage		V_{IOTM}	6000			V
Peak insulation voltage		V_{IORM}	560			V
Resistance (input to output)		R_{IO}		100		GΩ
Safety rating - power output		P_{SO}			350	mW
Safety rating - input current		I_{SI}			150	mA
Safety rating - temperature		T_{SI}			165	°C
External creepage distance			4			mm
External clearance distance			4			mm
Internal creepage distance			3.3			mm
Insulation thickness			0.2			mm

Note

As per IEC 60747-5-2, § 7.4.3.8.1, this optocoupler is suitable for “safe electrical insulation” only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.

TYPICAL CHARACTERISTICS

T_{amb} = 25 °C, unless otherwise specified

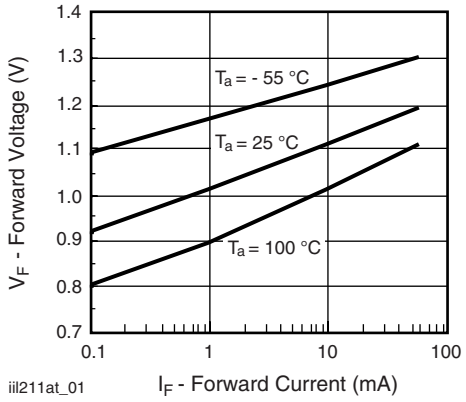


Fig. 3 - Forward Voltage vs. Forward Current

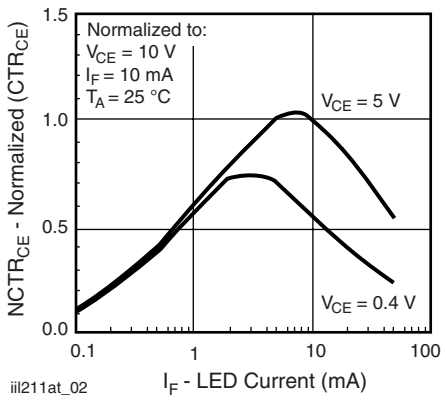


Fig. 4 - Normalized Non-Saturated and Saturated CTR_{CE} vs. LED Current

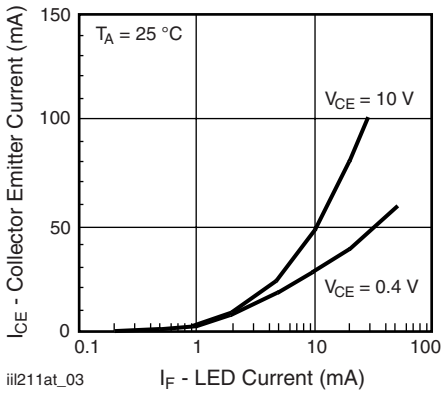


Fig. 5 - Collector Emitter Current vs. LED Current

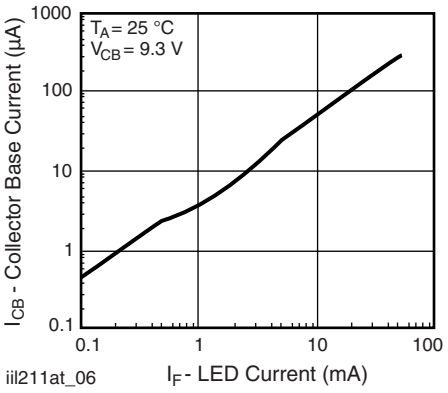


Fig. 8 - Collector Base Photocurrent vs. LED Current

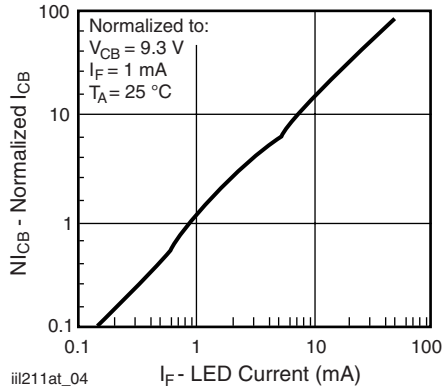


Fig. 6 - Normalized Collector Base Photocurrent vs. LED Current

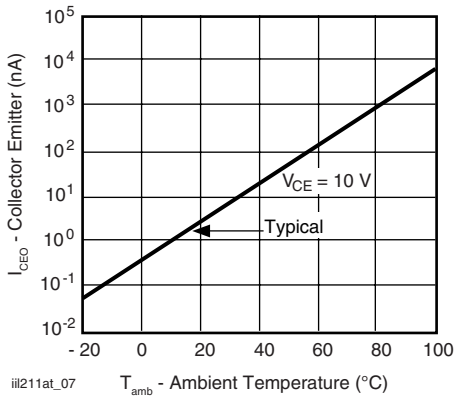


Fig. 9 - Collector Emitter Leakage Current vs. Temperature

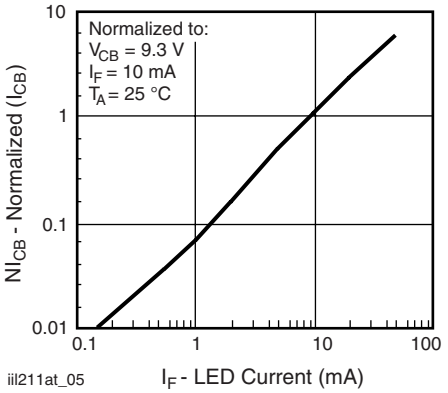


Fig. 7 - Normalized Collector Base Photocurrent vs. LED Current

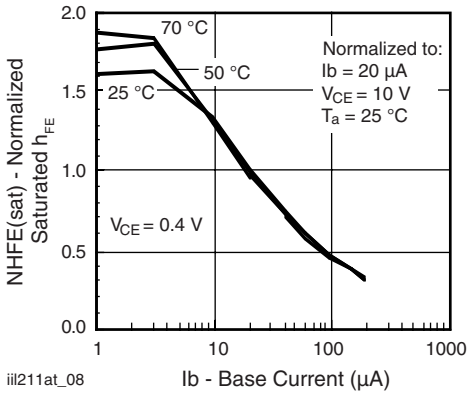


Fig. 10 - Normalized Saturated h_{FE} vs. Base Current and Temperature

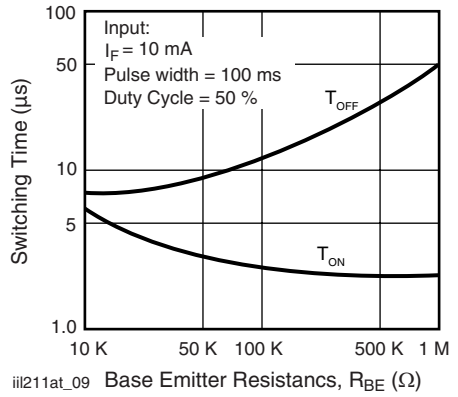


Fig. 11 - Typical Switching Characteristics vs. Base Resistance (Saturated Operation)

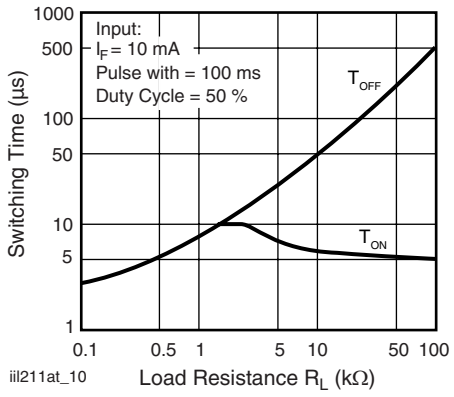
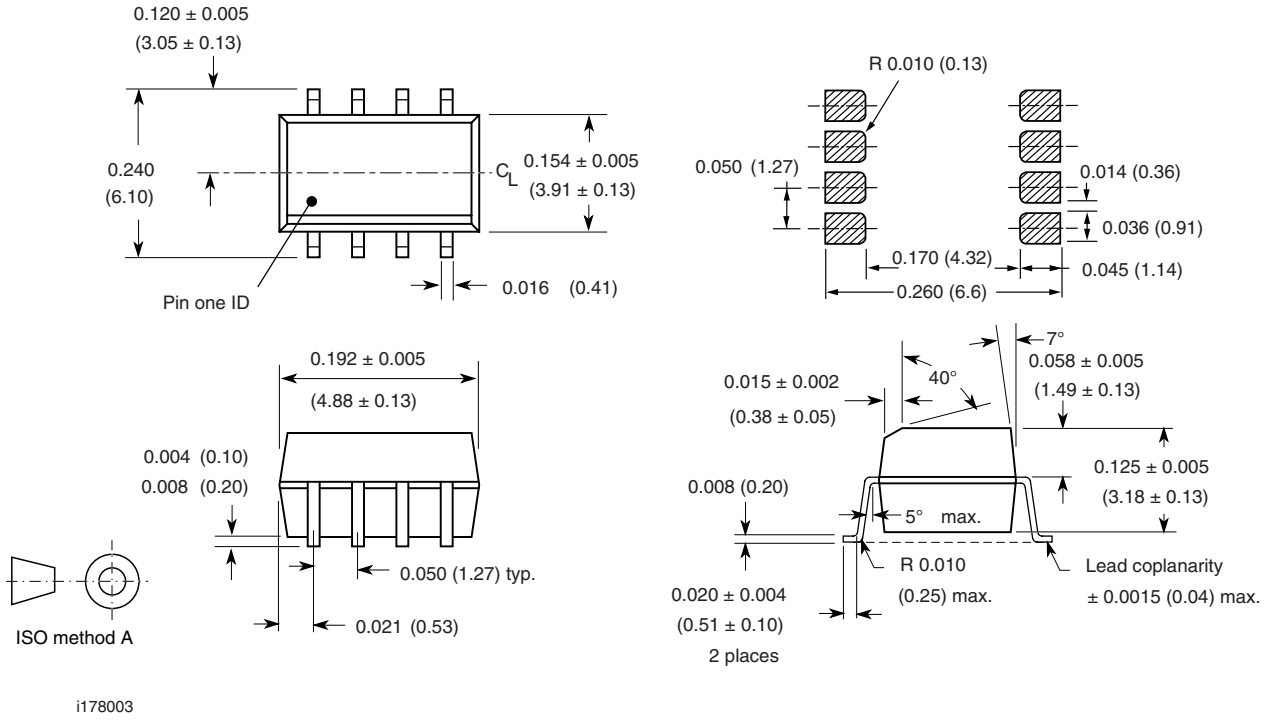


Fig. 12 - Typical Switching Times vs.Load Resistance

PACKAGE DIMENSIONS in inches (millimeters)



OZONE DEPLETING SUBSTANCES POLICY STATEMENT

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively.
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA.
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany

Disclaimer

All product specifications and data are subject to change without notice.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, “Vishay”), disclaim any and all liability for any errors, inaccuracies or incompleteness contained herein or in any other disclosure relating to any product.

Vishay disclaims any and all liability arising out of the use or application of any product described herein or of any information provided herein to the maximum extent permitted by law. The product specifications do not expand or otherwise modify Vishay’s terms and conditions of purchase, including but not limited to the warranty expressed therein, which apply to these products.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications unless otherwise expressly indicated. Customers using or selling Vishay products not expressly indicated for use in such applications do so entirely at their own risk and agree to fully indemnify Vishay for any damages arising or resulting from such use or sale. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

Product names and markings noted herein may be trademarks of their respective owners.

OCEAN CHIPS
Океан Электроники
Поставка электронных компонентов

Компания «Океан Электроники» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Поставка оригинальных импортных электронных компонентов напрямую с производств Америки, Европы и Азии, а так же с крупнейших складов мира;
- Широкая линейка поставок активных и пассивных импортных электронных компонентов (более 30 млн. наименований);
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Помощь Конструкторского Отдела и консультации квалифицированных инженеров;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Поставка электронных компонентов под контролем ВП;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- При необходимости вся продукция военного и аэрокосмического назначения проходит испытания и сертификацию в лаборатории (по согласованию с заказчиком);
- Поставка специализированных компонентов военного и аэрокосмического уровня качества (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Actel, Aeroflex, Peregrine, VPT, Syfer, Eurofarad, Texas Instruments, MS Kennedy, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Компания «Океан Электроники» является официальным дистрибьютором и эксклюзивным представителем в России одного из крупнейших производителей разъемов военного и аэрокосмического назначения «**JONHON**», а так же официальным дистрибьютором и эксклюзивным представителем в России производителя высокотехнологичных и надежных решений для передачи СВЧ сигналов «**FORSTAR**».

AVIC JONHON

«JONHON» (основан в 1970 г.)

Разъемы специального, военного и аэрокосмического назначения:

(Применяются в военной, авиационной, аэрокосмической, морской, железнодорожной, горно- и нефтедобывающей отраслях промышленности)

«FORSTAR» (основан в 1998 г.)

ВЧ соединители, коаксиальные кабели, кабельные сборки и микроволновые компоненты:

(Применяются в телекоммуникациях гражданского и специального назначения, в средствах связи, РЛС, а так же военной, авиационной и аэрокосмической отраслях промышленности).

FORSTAR®

Телефон: 8 (812) 309-75-97 (многоканальный)
Факс: 8 (812) 320-03-32
Электронная почта: ocean@oceanchips.ru
Web: http://oceanchips.ru/
Адрес: 198099, г. Санкт-Петербург, ул. Калинина, д. 2, корп. 4, лит. А